





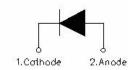
SDURK20Q60 ULTRAFAST RECTIFIER



Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Circuit Diagram



Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb Free Device
- Terminals finish: 100% Pure Tin
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings@TA=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	600	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=98°C, rectangular wave form	20	Α
Peak One Cycle Non-Repetitive Surge Current	Ігѕм	8.3ms, Half Sine pulse	190	А

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Electrical Characteristics@TA=25°C unless otherwise specified

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop *	V_{F1}	@20A, Pulse, T _J = 25°C	1.65	2.00	V
	V_{F2}	@20A, Pulse, T _J = 125°C	1.50	1.80	٧
	V _{F3}	@20A, Pulse, T _J = 150°C	1.43	-	>
Reverse Current *	I _{R1}	@V _R = rated V _R , T _J = 25°C	0.10	10	μΑ
	I _{R2}	$@V_R = \text{rated } V_R$, $T_J = 125^{\circ}C$	11	200	μΑ
	I _{R3}	$@V_R = \text{rated } V_R$, $T_J = 150^{\circ}\text{C}$	28	-	μΑ
Reverse Recovery Time	t _{rr}	I _F =500mA, I _R =1A,and I _{rm} =250mA	25	40	ns
Reverse Recovery Time	t _{rr}		58	-	ns
Reverse Recovery Charge	Q _{rr}	l _F = 20A, diF/dt = 200A/µs V _R = 400V, T _J = 25°C	186	-	nC
Reverse Recovery Current	I _{RRM}	- VR - 400V, 13 - 25 C	6.4	-	Α
Reverse Recovery Time	t _{rr}	I _F = 20A, diF/dt = 200A/µs	82	-	ns
Reverse Recovery Charge	Qrr	$V_R = 400V, T_J = 125^{\circ}C$	303	-	nC
Reverse Recovery Current	I _{RRM}		7.4	-	Α
Reverse Recovery Time	t _{rr}	I _F = 1A, diF/dt = 100A/µs	27	-	ns
Reverse Recovery Charge	Qrr	V _R = 30V, T _J = 25°C	19	-	nC
Reverse Recovery Current	I _{RRM}		1.4	-	Α
Reverse Recovery Time	t _{rr}	$I_F = 1A$, $diF/dt = 100A/\mu s$	57	-	ns
Reverse Recovery Charge	Qrr	V _R = 30V, T _J = 125°C	79	-	nC
Reverse Recovery Current	I _{RRM}		2.8	-	Α

^{*} Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications@T_A=25°C unless otherwise specified

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R _θ JC	DC operation	1.6	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	ITO-220AC-2L			

Ordering Information

Device	Package	Shipping	
SDURK20Q60	ITO-220AC-2L (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

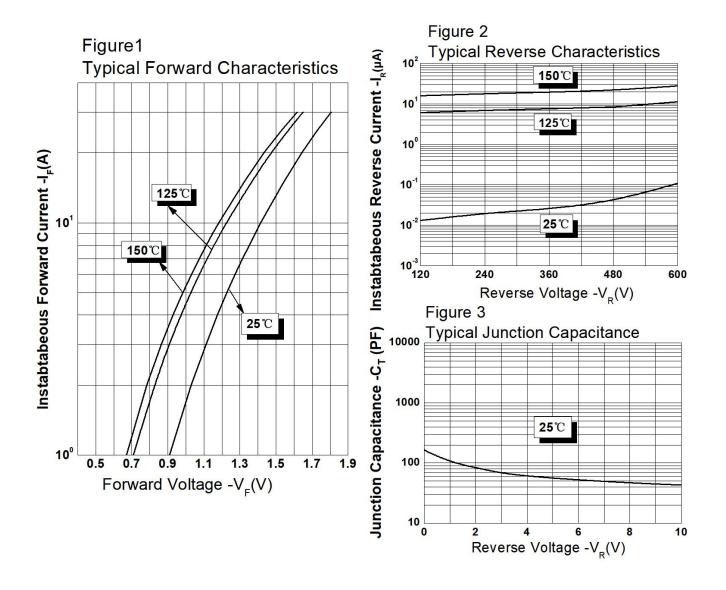
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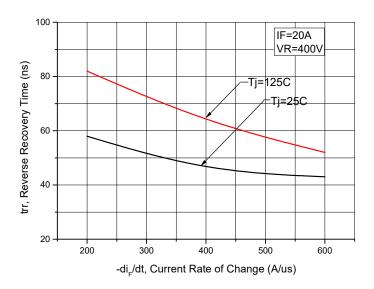
Ratings and Characteristics Curves











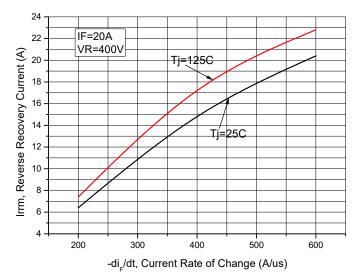
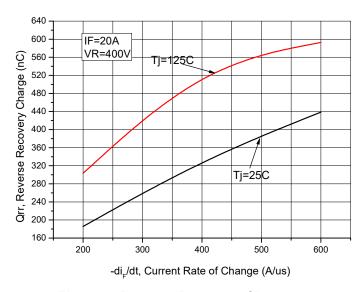


Figure 4. Reverse Recovery Time vs.

Current Rate of Change

Figure 5. Reverse Recovery Current vs.
Current Rate of Change



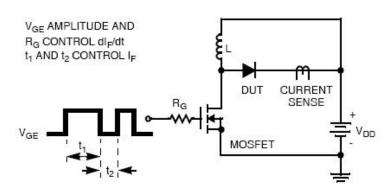


Figure 6. Reverse Recovery Charge vs. Current Rate of Change

Figure 7. Diode Test Circuit

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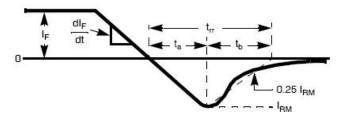
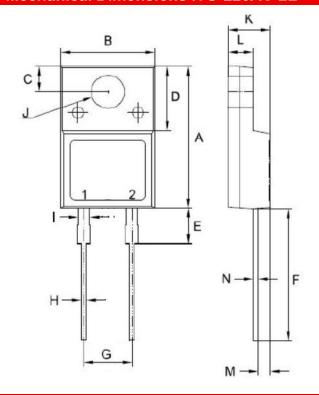


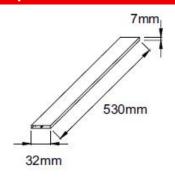
Figure 8 - Reverse Recovery Waveform

Mechanical Dimensions ITO-220AC-2L

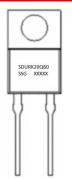


SYMBOL	Millimeters			
	MIN.	TYP.	MAX.	
Α	14.50	15.30	16.00	
В	9.50	10.00	10.50	
С	2.50	3.00	3.5	
D	6.30	6.80	7.30	
E	3.10	3.70	4.30	
F	13.00	13.5	14.00	
G	4.90	5.10	5.30	
Н	0.30	0.60	0.90	
I	0.90	1.2	1.50	
J	3.20	3.50	3.80	
K	4.24	4.54	4.84	
L	2.30	2.61	2.92	
М	1.09	1.29	1.49	
N	0.42	0.53	0.63	

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

SDUR = Device Type Κ = Package type 20 = Forward Current (20A) Q = Q = Reverse Voltage (600V) 60 SSG = SSG

= Year $\mathsf{W}\mathsf{W}$ = Week = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

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SDURK20Q60



Technical Data Data Sheet N2234, REV.A





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